



15:00-, 18. Nov. 2004

Condensed matter theory seminar
Univ. Regensburg, Germany

Transport through One-Dimensional Correlated Electrons with Electron-Phonon Interaction

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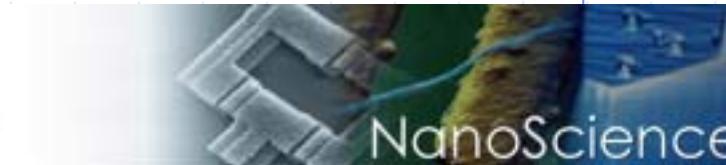
Kavli Institute of Nanoscience, TU Delft, The Netherlands



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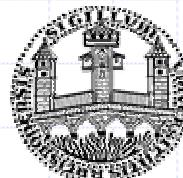


Graduiertenkolleg



Collaboration: Milena Grifoni

Dept. of Phys., Univ. of Regensburg, Germany

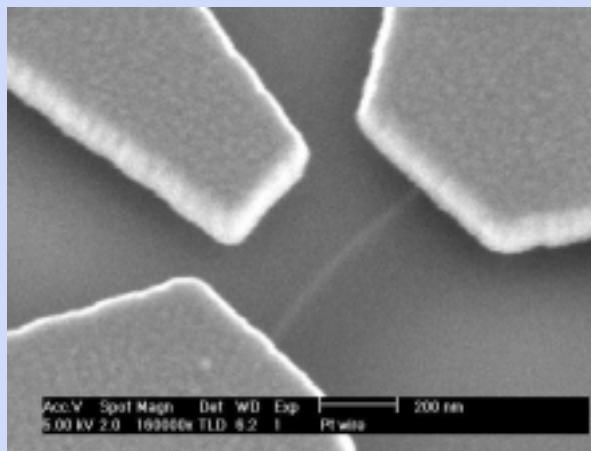
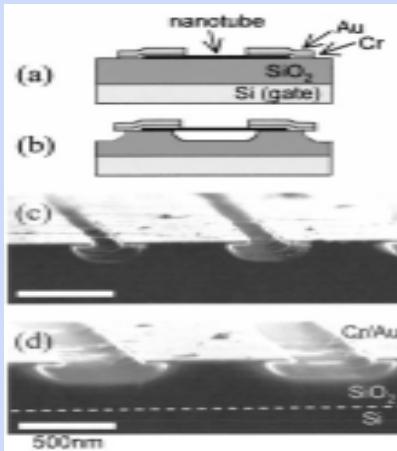


Thanks: Leonhard Mayrhofer (QTD, Univ. Regensburg), Graduiertenkolleg

Motivated by,

Free-standing Carbon Nanotube

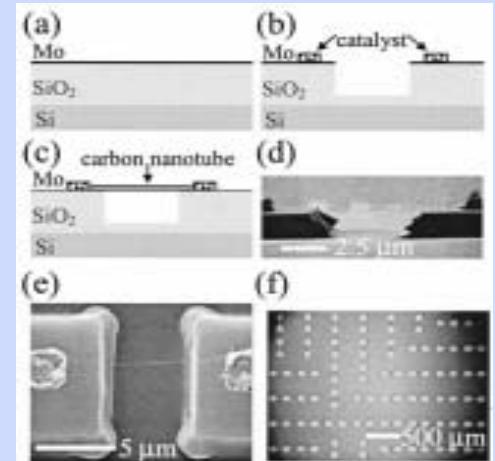
Under-etching



J. Nygard et al.:
Appl. Phys. Lett. 79, 4216 (2001)

S. Sapmaz et al. (TU Delft), unpublished.

Growth “bridge” in CVD



N. Franklin et al.:
Appl. Phys. Lett. 81, 913(2002)

What's expected in FSNT?

Contents

◆ Introduction

- Transport properties of CNT
- Free-standing NT

◆ Model & Current

- Model
- Current calculation

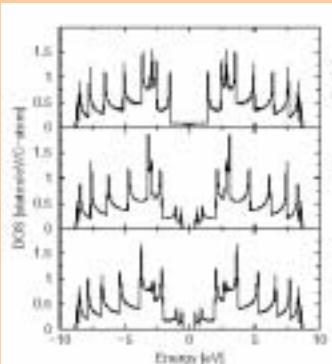
◆ Compare with EXP.

◆ Summary

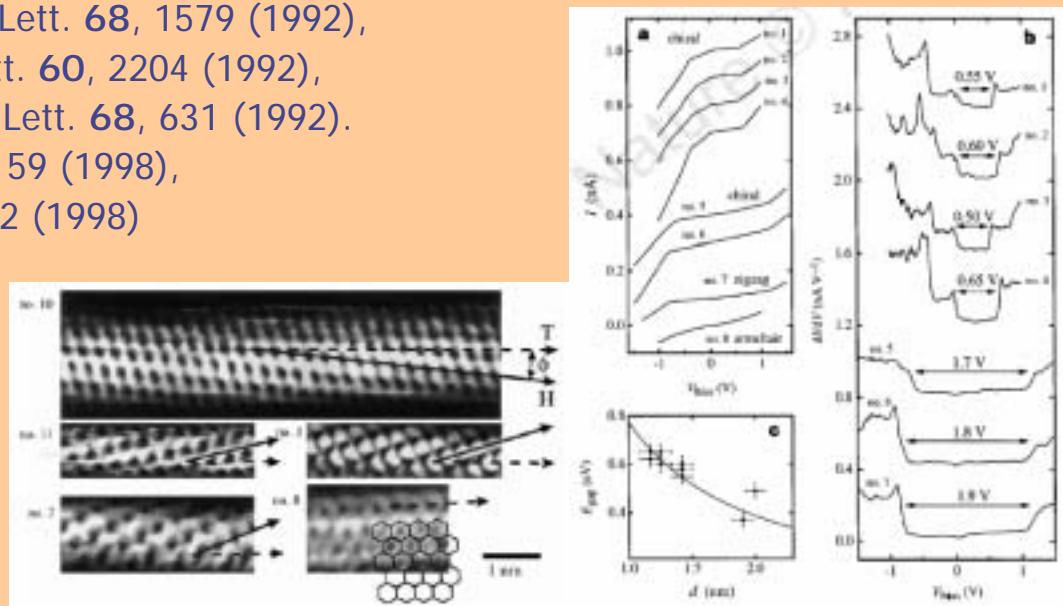
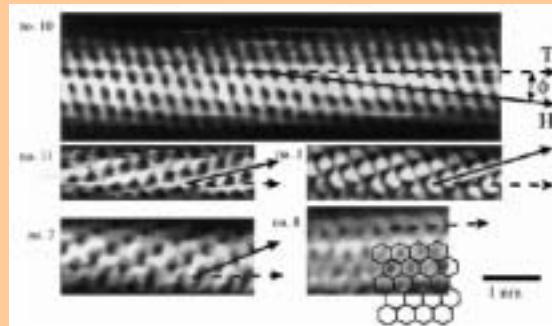
Transport through Carbon Nanotubes

◆ chirality: metal or semiconductor

- ◆ Hamada et al., Phys. Rev. Lett. **68**, 1579 (1992),
Saito et al., Appl. Phys. Lett. **60**, 2204 (1992),
Mintmire et al., Phys. Rev. Lett. **68**, 631 (1992).
- ◆ Wildoer et al. Nature **391**, 59 (1998),
Odom et al. Nature **391**, 62 (1998)



Tight-binding calc.: by Saito et al.

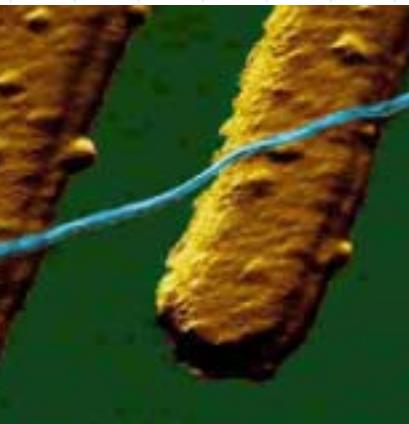


STM measurements: Wildoer et al. Nature **391**, 59 (1998)

single-particle quantum mechanics

◆ Electron correlation effect

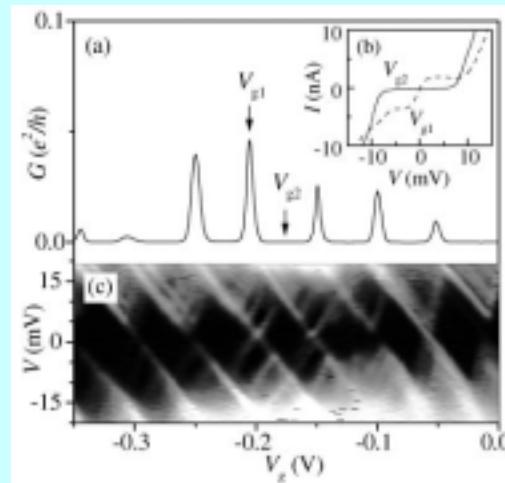
Electron correlation in nanotube I.



AFM image of an individual carbon nanotube between Pt electrodes spaced by 50 nm. Tans et al., Nature 386 (1997) 474.

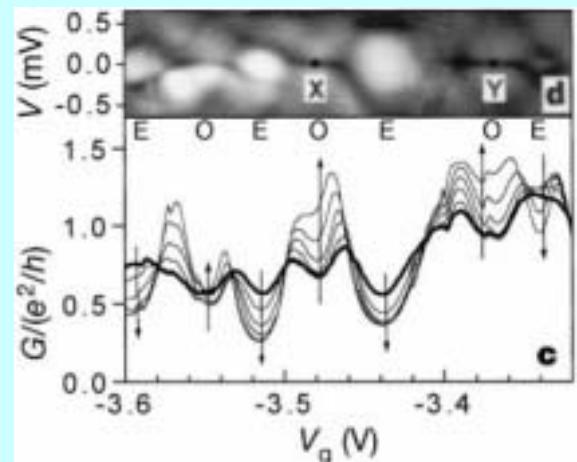
Similer effect to quantum dot:
Electron Correlation in
1-Dim “Quantum Dot”

Coulomb blockade



Nygard et al.: Appl. Phys. A 69, 297 (1999)

Kondo effect



Nygard et al.: Nature 408, 342 (2000)

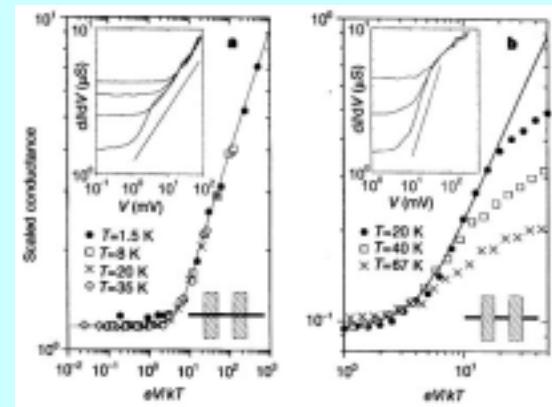
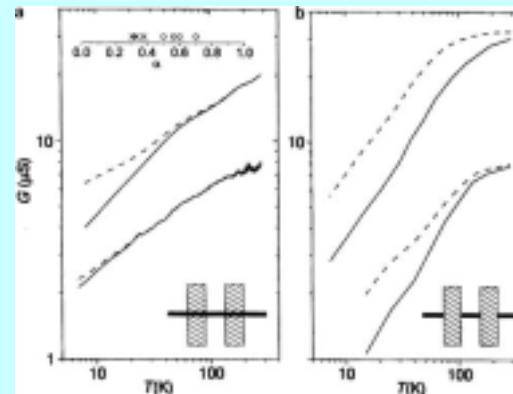
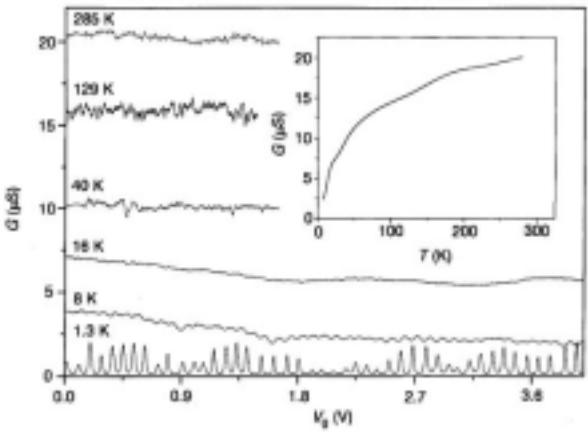
N_d changes one by one; reflecting strong U

Electron correlation in nanotube II.

Electron Correlation in “One-Dimension Conductor”

Tomonaga-Luttinger liquid:

- power-law of G : $G \sim \omega^{\alpha_{\text{end}}}$, $G \sim \omega^{\alpha_{\text{bulk}}}$

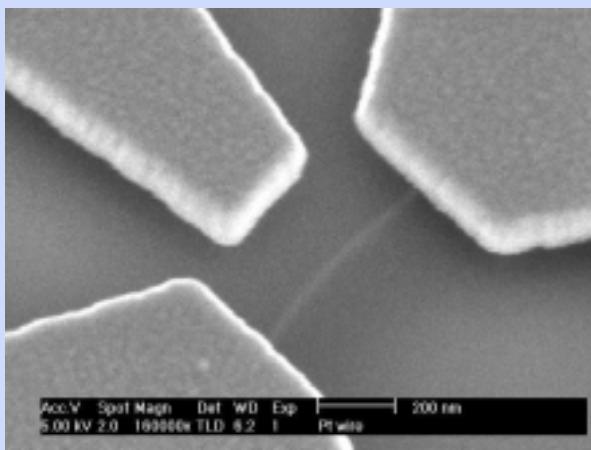
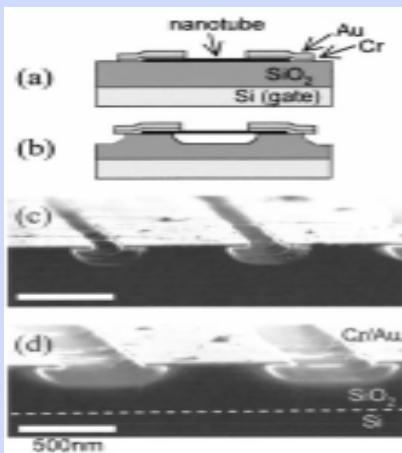


M. Bockrath et al.: Nature 397, 598 (1999)

Coulomb blockade, Kondo effect, TL Liquid
→ Importance of Electron Correlation in CNT

Free-standing Nanotubes

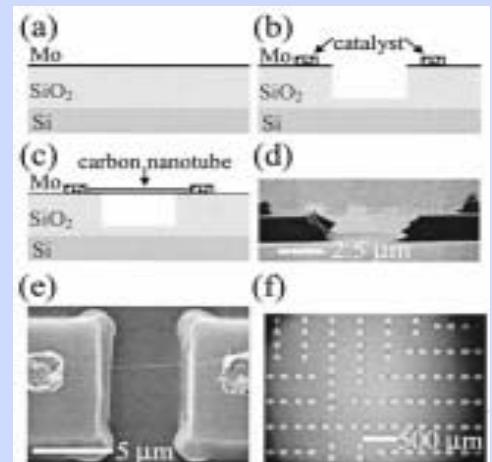
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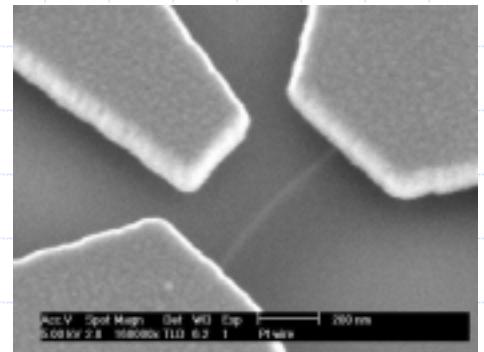


N. Franklin et al.:
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What's expected in FSNT?

Free-standing Carbon Nanotube

- ◆ Suppression of disorder: without substrate
- ◆ “Beam” fixed at its ends
 - Bending:
 - ◆ Change the capacitance
 - Sapmaz et al. PRB **67**, 235414 (2003)
 - **Vibration:**
 - ◆ induce phonon excitation in NT



Sapmaz et al. Unpublished.

— Purpose —

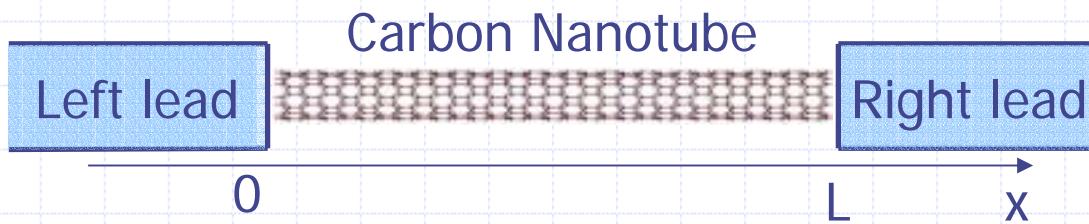
How the mechanical motion affects the electrons?



This talk: “1-dim. corr. electrons + el.-phonon coupling” in CNT

Model of FSNT

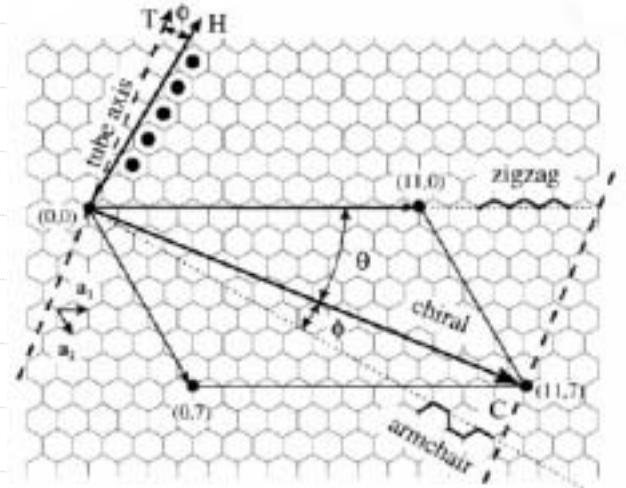
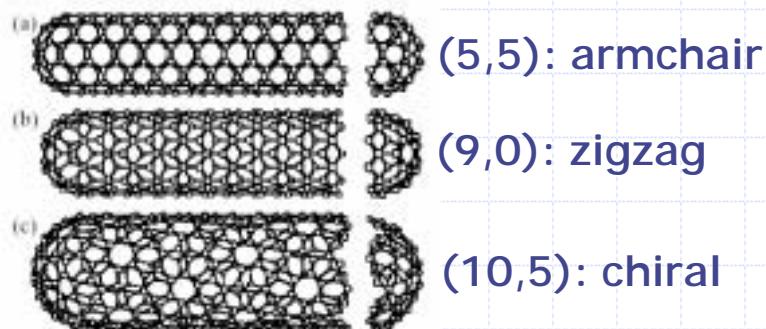
◆ Hamiltonian of the systems



- metallic Single-Walled NT
- Finite length, L , of CNT

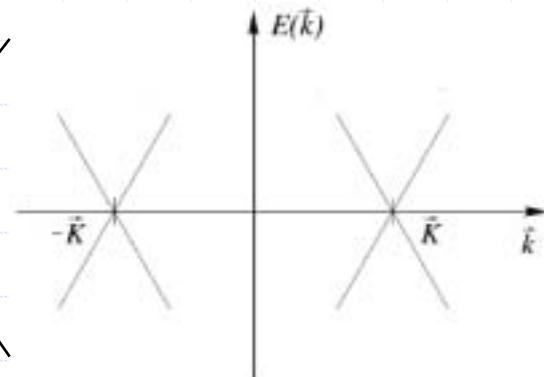
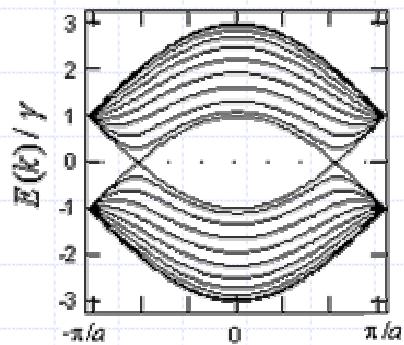
Electronic structure of SWNT

- Single-Walled Carbon Nanotube
 - wrapped graphite sheet
 - wrapping vector: $na_1 + ma_2 := (n, m)$



a_1, a_2 : graphite primitive lattice vectors

- $n-m=3l$: metal, 2 bands at E_F
 - 1D conductor with 2 linear bands in low energy



TL model for electrons in CNT

- 1-dim. correlated electrons: TL liquid
- 2 bands in CNT \rightarrow 4 sectors (total charge, total spin, relative charge, relative spin; $j=\rho+, \sigma+, \rho-, \sigma-$)
- Long-range Coulomb interaction:
 - only forward scattering: interaction parameters $g_{\rho+} < 1$, $g_{\rho-} = g_{\sigma+} = g_{\sigma-} = 1$
- Finite length:
 - open boundary condition
 - discreteness of the excitations
 - charging energy

1-dim. bosonized Hamiltonian:

$$H = \sum_j H_j$$

$$H_j = \frac{v_j}{2} dx \int_0^L \left[g_j \Pi_j^2(x) + \frac{1}{g_j} (\partial_x \phi_j(x))^2 \right]$$

$$= \sum_{n \geq 1} \Delta \epsilon_j n \left(b_{jn}^+ b_{jn}^- + \frac{1}{2} \right) + \frac{\Delta \epsilon_j}{8g_j} N_j^2$$

Egger et al., PRL 79, 5082 (1997), Eur. Phys. J. B 3, 281 (1998)
 Kane et al., PRL 79, 5086 (1997).

$$g_{\rho+} = g = 1 / \sqrt{\left(1 + \frac{U}{\pi \hbar v_F}\right)}, \quad \left(U = 8e^2 \log \frac{R_s}{R}\right), \quad g_j = 1 \quad (j = \rho-, \sigma+, \sigma-)$$

$$v_j = \frac{v_F}{g_j}, \quad \Delta \epsilon_0 = \hbar v_F \frac{\pi}{L}, \quad \Delta \epsilon_j = \frac{\Delta \epsilon_0}{g_j}$$

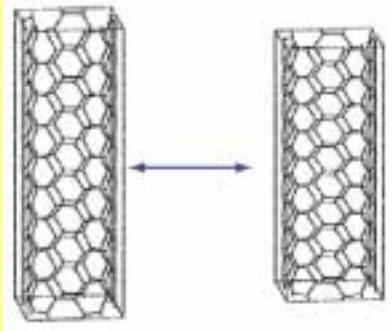
$$\phi(x) = \sqrt{\frac{2}{L}} \sum_{n \geq 1} \sin(k_n x) \phi_n, \quad \phi_n = \sqrt{\frac{\hbar g}{2k_n}} (b_n^+ + b_n^-) \quad k_n = \frac{n\pi}{L}$$

$$\Pi(x) = \sqrt{\frac{2}{L}} \sum_{n \geq 1} \sin(k_n x) \Pi_n, \quad \Pi_n = i \sqrt{\frac{\hbar k_n}{2g}} (b_n^+ - b_n^-)$$

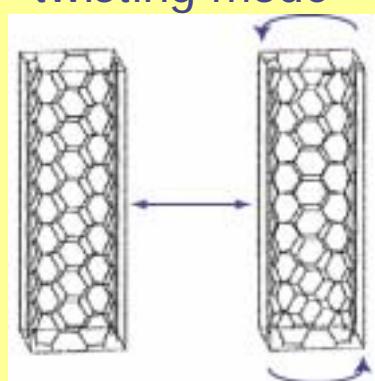
N_j = ground state occupation number in j sector

Phonons in CNT

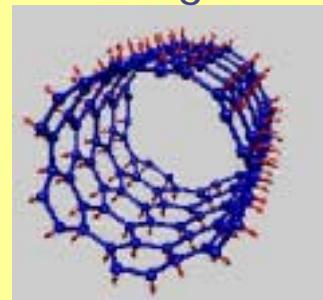
stretching mode



twisting mode



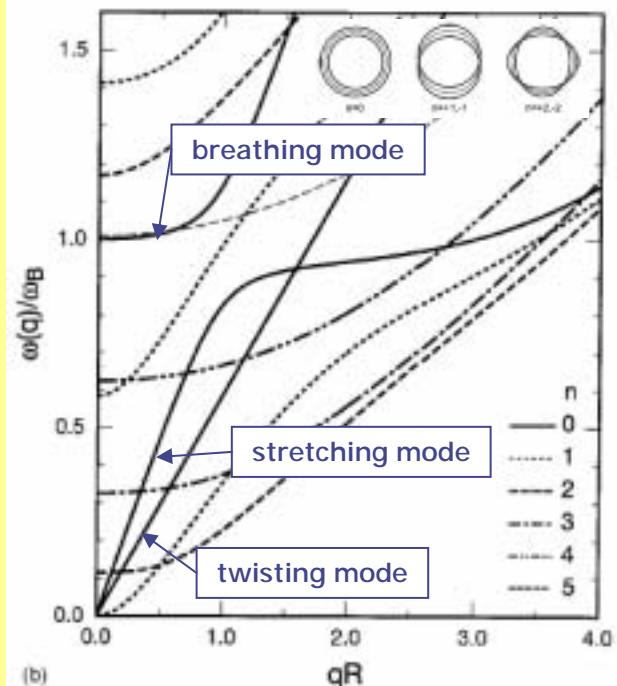
breathing mode



http://www-g.eng.cam.ac.uk/edm/research/ramanlab/raman_CNTs.html

- Phonon modes in CNT
 - Stretching mode:
 \leftrightarrow LA phonon in 1-dim.
 - Twisting mode:
 doesn't couple to electrons
 - Breathing mode:
 finite energy ω_B at $k=0$,
 negligible in low energy properties

phonon dispersion relation



(b)

Suzure et al., PRR 65, 225412 (2002)

Phonon in CNT

- LA phonon in 1-dim. (<-> stretching mode)
- continuum model

Phonon Hamiltonian: Longitudinal wave ($u_x \neq 0$)

$$H_{ph}^{lon} = \int_0^L dx \left[\frac{1}{2\rho S} P_x^2(x) + \frac{ES}{2} (\partial_x u_x(x))^2 \right]$$

$$= \sum_{n \geq 1} \Delta \varepsilon_a n \left(a_n^+ a_n + \frac{1}{2} \right)$$

ρ : Density of mass
 E : Young's modulus
 S : Cross-section

$$\Delta \varepsilon_a = \sqrt{\frac{E}{\rho}} \frac{\pi}{L}$$

u_x : displacement

P : conjugate momentum

$$u_x(x) = \sqrt{\frac{2}{L}} \sum_{n \geq 1} \sin(k_n x) u_{x,n}, \quad u_{x,n} = \sqrt{\frac{\hbar}{2\rho S \omega_n^{lon}}} (a_n^+ + a_n)$$

$$\Pi_x(x) = \sqrt{\frac{2}{L}} \sum_{n \geq 1} \sin(k_n x) \Pi_{x,n}, \quad \Pi_{x,n} = i \sqrt{\frac{\hbar \rho S \omega_n^{lon}}{2}} (a_n^+ - a_n)$$

Electron-phonon interaction

Deformation potential:

- $\propto \partial_x u_x(x)$
- interact with total charge density: couple only to $H_{\rho+}$ term

Electron-phonon interaction:

$$\begin{aligned} H_{el-ph}^{lon} &= c_{lon} \int dx \psi^+(x) \psi(x) \partial_x u_x(x) \\ &= c_{lon} \int_0^L dx \left\{ \frac{1}{\sqrt{\pi\hbar}} \sqrt{\frac{2}{L}} \sum_{n \geq 1} k_n \cos(k_n x) \phi_{\rho+,n} + \rho_{q=0} \right\} \left\{ \sqrt{\frac{2}{L}} \sum_{n \geq 1} k_n \cos(k_n x) u_{x,n} \right\} \\ &= \sum_{n \geq 1} \Delta I^{lon} n (b_{\rho+,n}^+ + b_{\rho+,n}) (a_n^+ + a_n) \end{aligned}$$

$$\Delta I^{lon} = c_{lon} \sqrt{\frac{\hbar g_{\rho+}}{4\pi S \sqrt{\rho E}}} \frac{\pi}{L}$$

$$\psi^+(x) \psi(x) = \frac{1}{\sqrt{\pi\hbar}} \partial_x \phi(x) + \rho_{q=0}$$

Diagonalization of the Hamiltonian

Total Hamiltonian: Bi-linear, diagonalized exactly

$$\begin{aligned} H_{\rho, \text{total}} &= H_{\rho+} + H_{ph}^{\text{lon}} + H_{el-ph}^{\text{lon}} \\ &= \sum_{n \geq 1} \Delta \varepsilon_{\rho+} n \left(b_{\rho+,n}^+ b_{\rho+,n} + \frac{1}{2} \right) + \sum_{n \geq 1} \Delta \varepsilon_a n \left(a_n^+ a_n + \frac{1}{2} \right) + \sum_{n \geq 1} \Delta I^{\text{lon}} n (b_{\rho+,n}^+ + b_{\rho+,n})(a_n^+ + a_n) \end{aligned}$$

Bogoliubov transformation

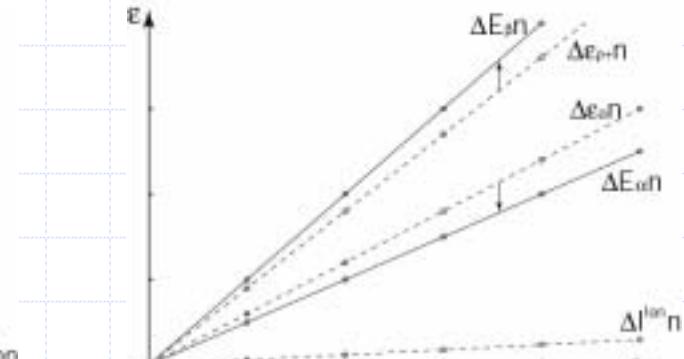
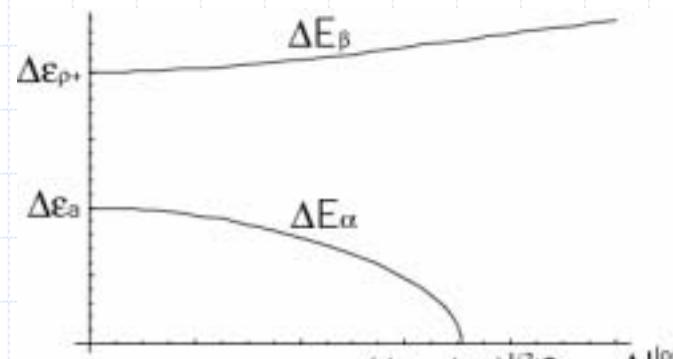
$$= \sum_{n \geq 1} \Delta E_\beta n \beta_n^+ \beta_n + \sum_{n \geq 1} \Delta E_\alpha n \alpha_n^+ \alpha_n + \text{Const.}$$

cf.

Engelsberg et al. PR **6A**, A1582 (1964),
Kleinert et al. Phys. Stat. Sol. (b) **199**, 435 (1997)
etc...

where,

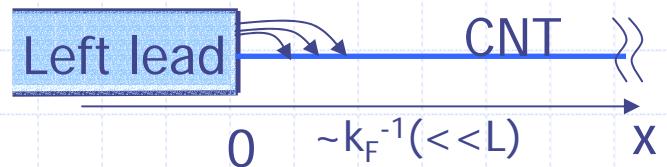
$$\Delta E_{\beta/\alpha} = \sqrt{\frac{(\Delta \varepsilon_{\rho+})^2 + (\Delta \varepsilon_b)^2}{2}} \pm \sqrt{\left(\frac{(\Delta \varepsilon_{\rho+})^2 - (\Delta \varepsilon_b)^2}{2} \right)^2 + 4 \Delta I^{\text{lon}} (\Delta \varepsilon_{\rho+})(\Delta \varepsilon_b)}$$



Current through CNT

- ◆ Current formula
- ◆ Effect of deformation potential
 - infinite length: $L \rightarrow \infty$
 - finite length: $L \neq \infty$

Current through CNT



Current:

- high enough barrier: lowest order of tunneling
- tunneling occurs only at the edge ($\sim k_F^{-1} \ll L$) region

Differential conductance:

$$\Rightarrow \frac{dI}{dV_{bias}} \propto -\frac{1}{\pi} \text{Im} G_{1\text{dim}}((x, x') = 0_+; V_{bias}) \equiv \rho_{end}(V_{bias})$$

DOS of end of NT

Infinite length limit ($L \rightarrow \infty$)

Infinite length limit; high temperature ($T \gg \Delta E \sim 1/L$)

spinless, single-band, for simplicity.

$$\rho_{end}(\omega) \propto |\omega|^{\frac{1}{g}-1} \rightarrow |\omega|^{\frac{1}{g'}-1}$$

$$(g')^{-1} = \left(\frac{\Delta E_\alpha}{\Delta \varepsilon_{\rho^+}} \sin^2 \varphi + \frac{\Delta E_\beta}{\Delta \varepsilon_{\rho^+}} \cos^2 \varphi \right) g^{-1}$$
$$\approx (1 - a(\Delta I^{lon})^2) g^{-1}$$

$$\tan 2\varphi = -\frac{4\Delta I^{lon} \sqrt{\Delta \varepsilon_a \Delta \varepsilon_{\rho^+}}}{\Delta \varepsilon_a^2 - \Delta \varepsilon_{\rho^+}^2}$$

ΔI^{lon} : electron-phonon interaction (> 0),
a: constant (> 0)

g' : Renormalized interaction parameter ($> g$)
“contribution of attractive interaction”

For Carbon Nanotube:

$$\rho_{end}(\omega) \propto |\omega|^{\frac{1}{4}\left(\frac{1}{g_{\rho^+}} + 3\right)-1} \rightarrow |\omega|^{\frac{1}{4}\left(\frac{1}{g_{\rho^+}} + 3\right)-1}$$

Finite length CNT ($L \neq \infty$)

Density of states at the end of CNT: $L \neq \infty$, $T \ll \Delta E$

$$\rho_{end}(\omega) = \sum_{p,q,r} C_{\alpha,p} C_{\beta,q} C_{\gamma,r} \delta(\omega - (E_c + p\Delta E_\alpha + q\Delta E_\beta + r\Delta \varepsilon_0)) \\ + \sum_{p,q,r} C_{\alpha,p} C_{\beta,q} C_{\gamma,r} \delta(\omega + (E_c + p\Delta E_\alpha + q\Delta E_\beta + r\Delta \varepsilon_0))$$

C_p : intensity of peaks

E_c : charging energy

ΔE_j : discreteness

$$C_{\alpha,p} = C_{\alpha,p}^{T=0} + \alpha e^{-\Delta E_\alpha / k_B T} (C_{\alpha,p+1}^{T=0} + C_{\alpha,p-1}^{T=0} - 2C_{\alpha,p}^{T=0})$$

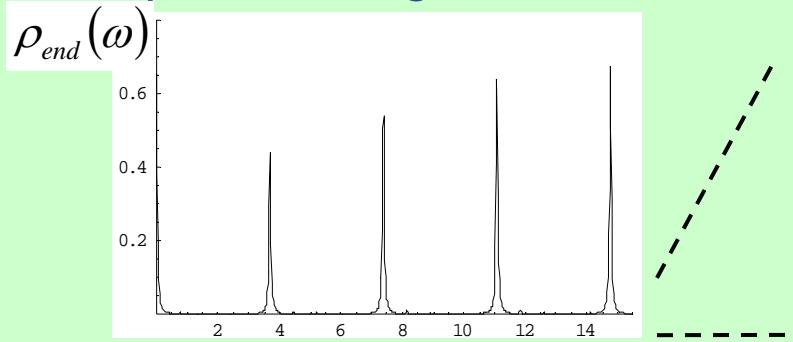
$$C_{\alpha,p}^{T=0} = \frac{\Gamma(\alpha + p)}{p! \Gamma(\alpha)} \Theta(p)$$

$$\alpha = \frac{1}{4} \frac{1}{g} \frac{\Delta E_\alpha}{\Delta \varepsilon_b} \sin^2 \varphi : \text{phonon}$$

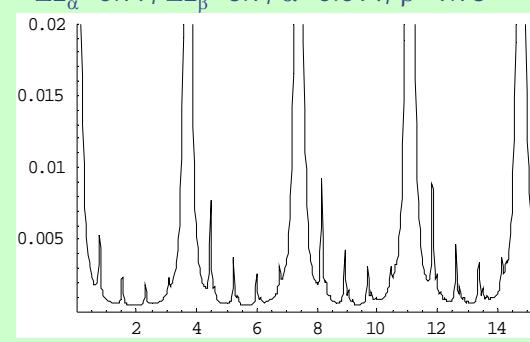
$$\beta = \frac{1}{4} \frac{1}{g} \frac{\Delta E_\beta}{\Delta \varepsilon_b} \cos^2 \varphi : \text{charge}$$

$$\gamma = \frac{3}{4} : \text{neutral modes}$$

spinless, single-band



$g=0.55$, $\Delta \varepsilon_a=1$, $\Delta \varepsilon_b=3.6$, $I=0.6$
 $\Delta E_\alpha=0.77$, $\Delta E_\beta=3.7$, $\alpha=0.014$, $\beta=1.78$



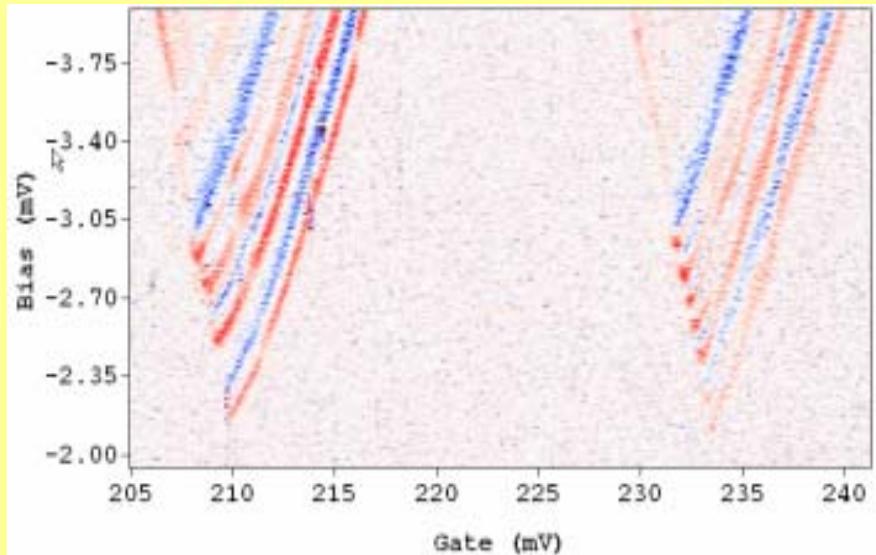
Discrete peaks

- discrete energies of charge density, neutral modes: ΔE_β , $\Delta \varepsilon_0$
- n-phonons assisted tunneling: ΔE_α

Peak height: power law ($C_p \sim \omega^{\alpha-1}$)

Compare with experiment

P. Jarillo-Herrero *et al* (TU Delft), unpublished.



- measure for $L=1200\text{nm}$ metallic FS-SWNT, @ $T=300\text{mK}$
- excitation peaks outside of Coulomb diamonds:
 - ◆ almost same period: $\Delta E_{\text{exp}} \sim 0.1 \text{ to } 0.2\text{meV}$

Estimated values; (for $L=1\mu\text{m}$)

$$g_{\rho+} \sim 0.25 \sim 0.3, \Delta \varepsilon_0 = \hbar v_F \pi / L = 0.7\text{meV}, \Delta \varepsilon_a = 0.06\text{meV}, \Delta I^{\text{ion}} = 0.01\text{meV}$$
$$\rightarrow \Delta E_\alpha = 0.06\text{meV}, \Delta E_\beta = 2.8\text{meV}$$

$\Delta E_{\text{exp}} \sim 2\Delta E_\alpha, 0.15\Delta \varepsilon_0, 0.1\Delta E_\beta$: come from phonon?

Summary & Future

◆ phonon effect in CNT

- changing of power
- phonon excitation peaks
- compare with exp. (phonon peaks?)

◆ Other interests

- gate voltage effect
 - ◆ Coulomb blockade
 - ◆ Int. between el. and TA phonon

